

Fuji Discrete Package IGBT

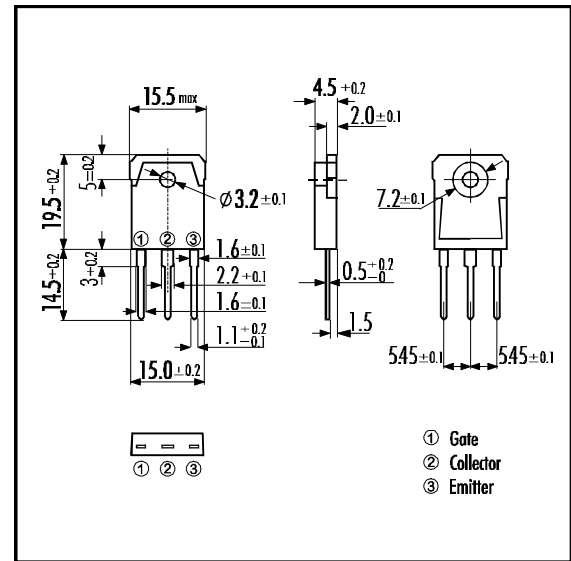
■ Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Minimized Internal Stray Inductance

■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

■ Outline Drawing

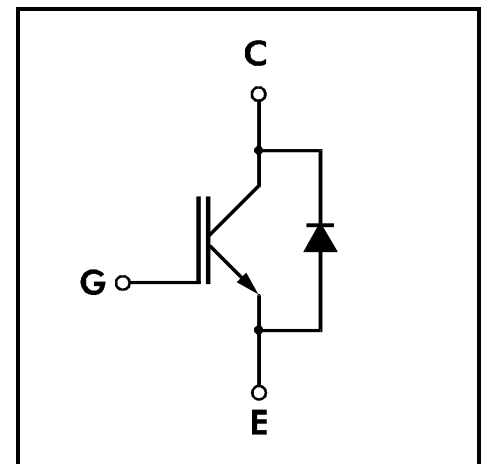


■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings ($T_c=25^\circ\text{C}$)

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V_{CES}	600	V
Gate -Emitter Voltage	V_{GES}	± 20	V
Collector Current	DC $T_c=25^\circ\text{C}$	I_{C25}	38
	DC $T_c=100^\circ\text{C}$	I_{C100}	20
	1ms $T_c=25^\circ\text{C}$	I_{CPULSE}	152
IGBT Max. Power Dissipation	P_C	145	W
FWD Max. Power Dissipation	P_C	75	W
Operating Temperature	T_i	+150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 ~ +150	$^\circ\text{C}$
Mounting Screw Torque		50	Nm

■ Equivalent Circuit



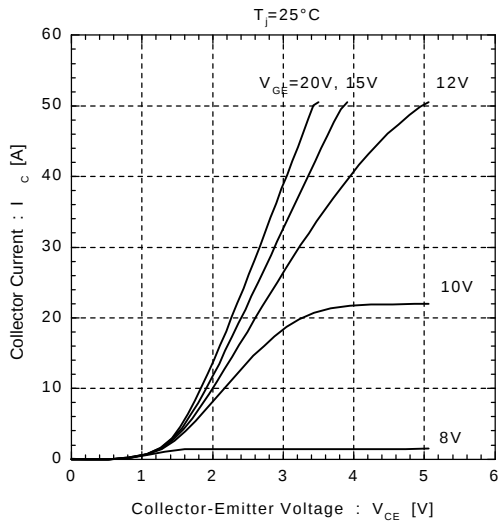
• Electrical Characteristics (at $T_j=25^\circ\text{C}$)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I_{CES}	$V_{GE}=0V$ $V_{CE}=600V$			1.0	mA
Gate-Emitter Leakage Current	I_{GES}	$V_{CE}=0V$ $V_{GE}=\pm 20V$			20	μA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=20V$ $I_C=20\text{mA}$	5.5		8.5	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V$ $I_C=20A$			3.0	V
Input capacitance	C_{ies}	$V_{GE}=0V$		1300		pF
Output capacitance	C_{oes}	$V_{CE}=10V$		300		
Reverse Transfer capacitance	C_{res}	$f=1\text{MHz}$		70		
Switching Time	Turn-on Time	t_{ON}			1.2	μs
		t_r			0.6	
	Turn-off Time	t_{OFF}			1.0	
		t_f			0.35	
	Turn-on Time	t_{ON}		0.16		μs
		t_r		0.11		
	Turn-off Time	t_{OFF}		0.30		
		t_f			0.35	
Diode Forward On-Voltage	V_F	$I_F=20A$ $V_{GE}=0V$			3.0	V
Reverse Recovery Time	t_{rr}	$I_F=20A$, $V_{GE}=-10V$, $di/dt=100A/\mu\text{s}$			300	ns

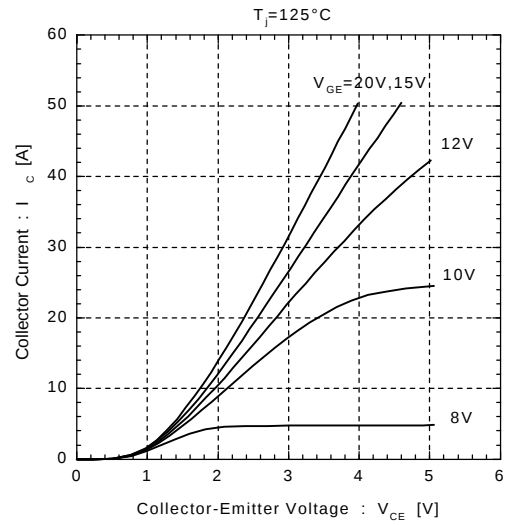
• Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	$R_{th(j-c)}$	IGBT			0.86	$^\circ\text{C/W}$
	$R_{th(j-e)}$	Diode			1.66	

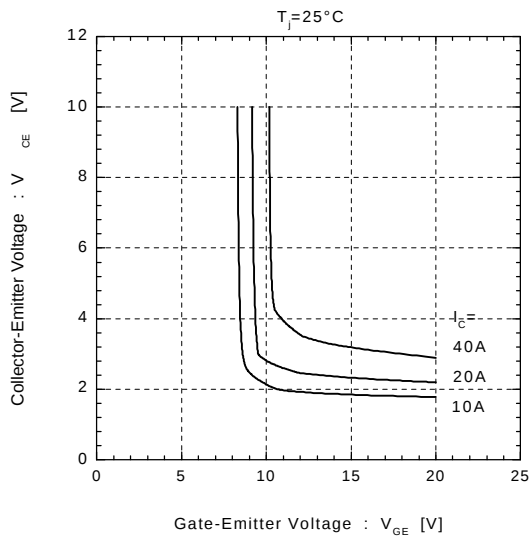
Collector Current vs. Collector-Emittor Voltage



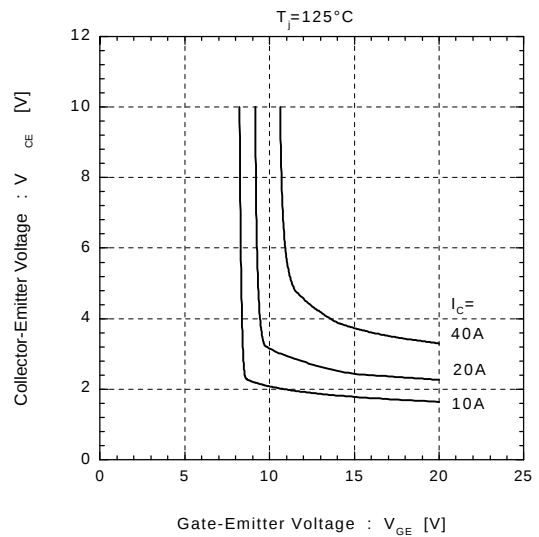
Collector Current vs. Collector-Emittor Voltage



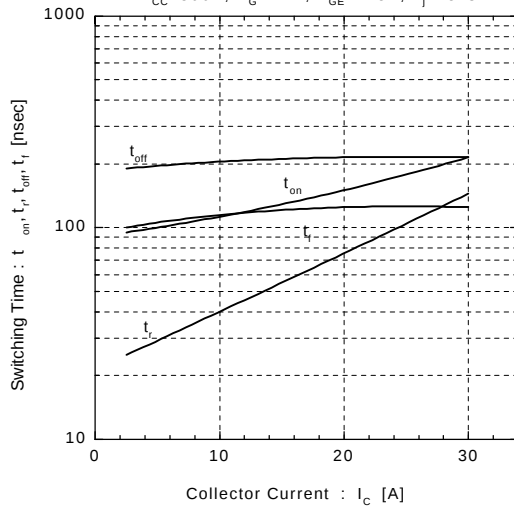
Collector-Emittor Voltage vs. Gate-Emittor Voltage



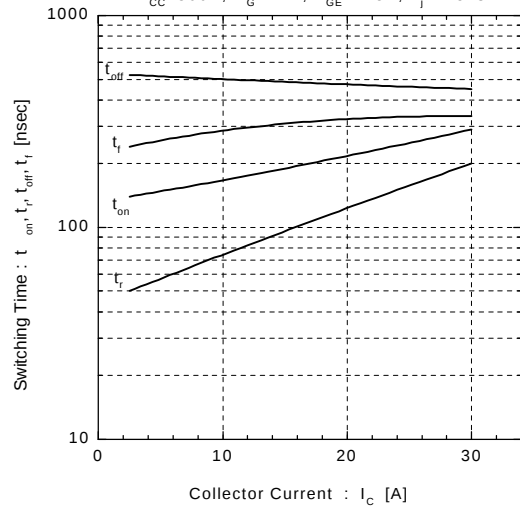
Collector-Emittor Voltage vs. Gate-Emittor Voltage

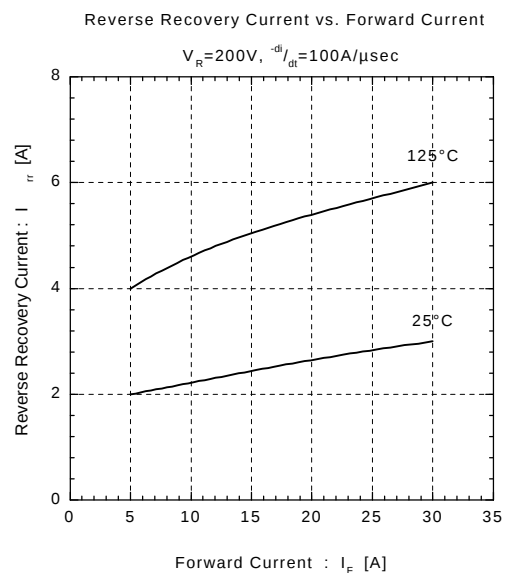
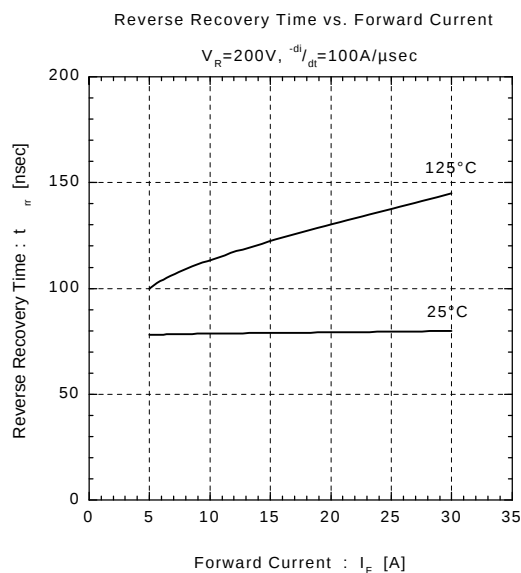
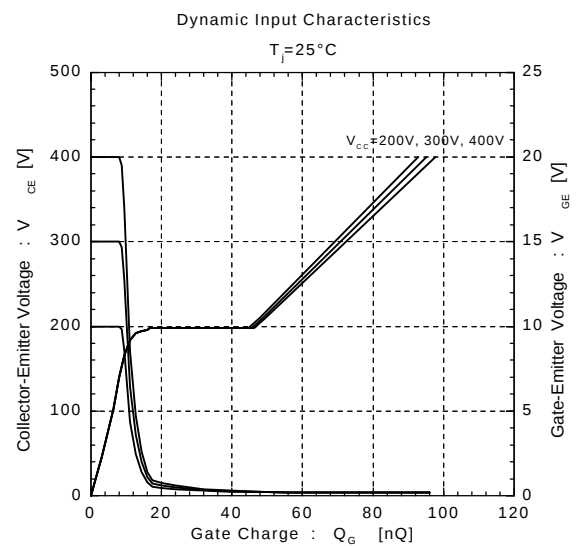
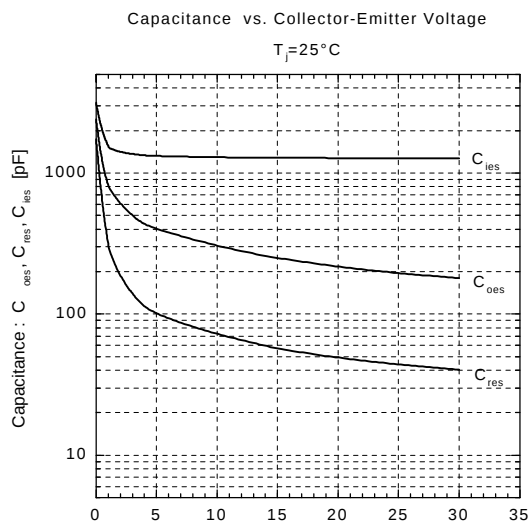
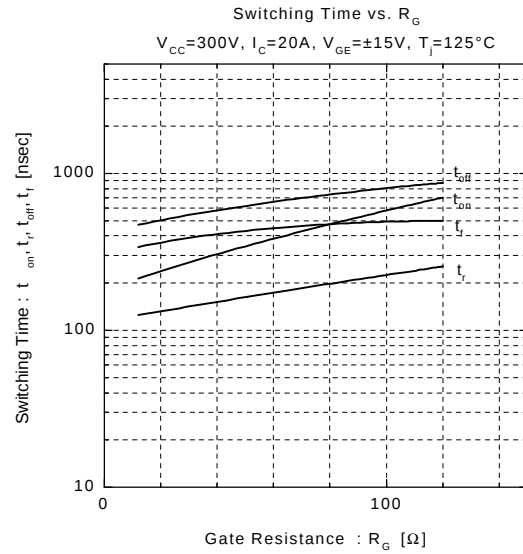
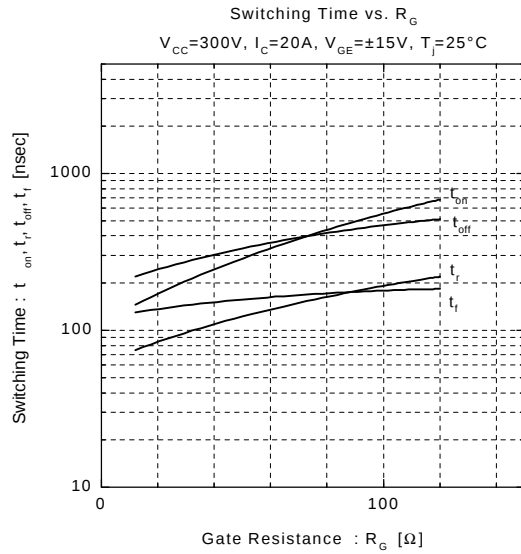


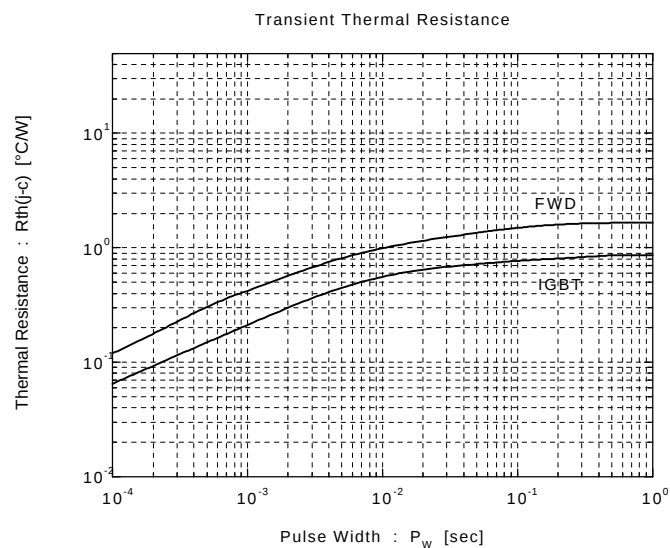
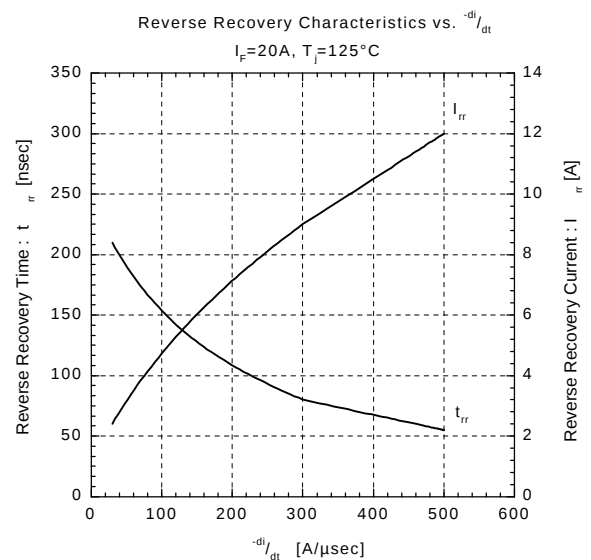
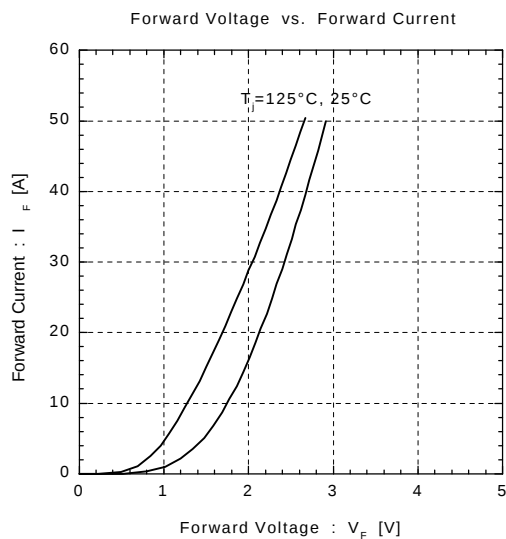
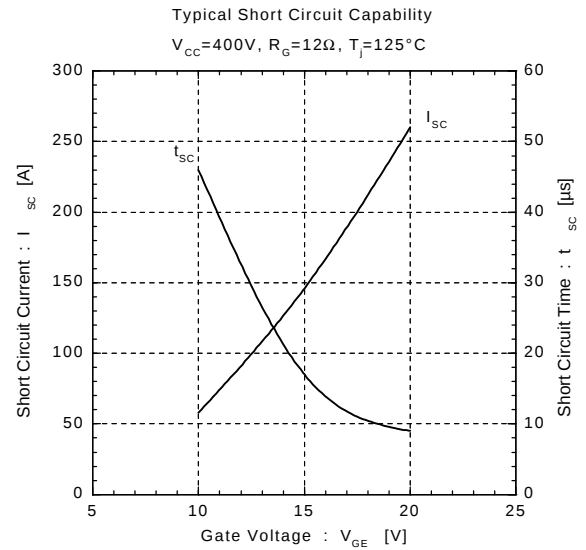
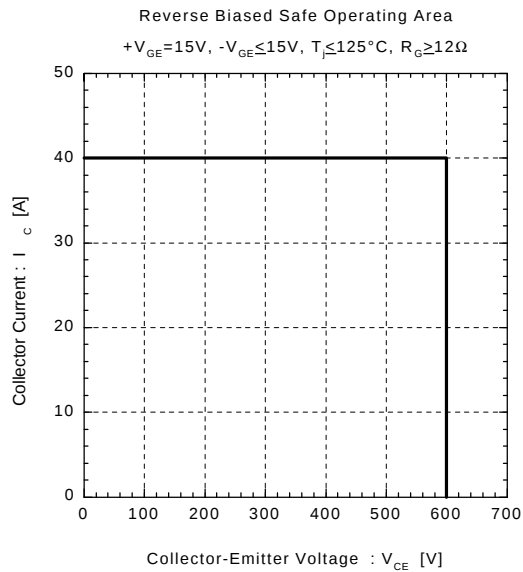
Switching Time vs. Collector Current
 $V_{CC} = 300V, R_G = 12\Omega, V_{GE} = \pm 15V, T_J = 25^\circ\text{C}$



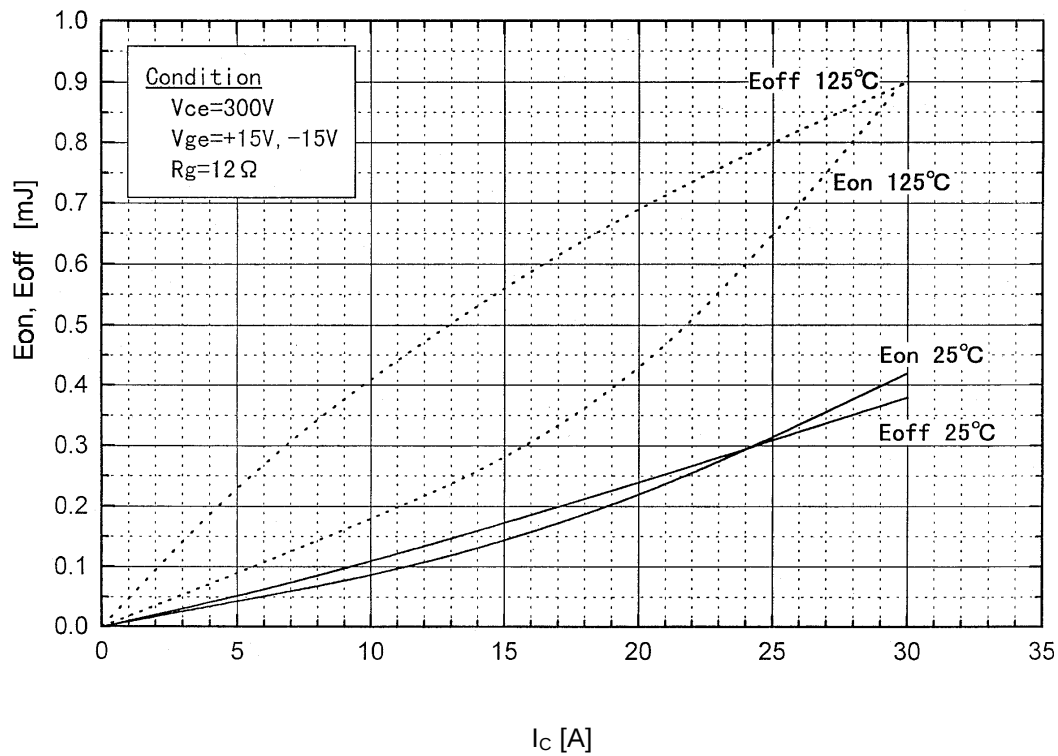
Switching Time vs. Collector Current
 $V_{CC} = 300V, R_G = 12\Omega, V_{GE} = \pm 15V, T_J = 125^\circ\text{C}$



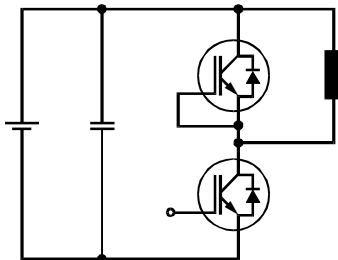




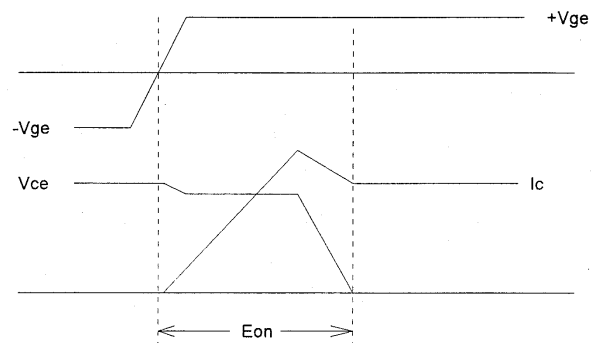
Switching losses (E_{on} , E_{off} vs. I_c)



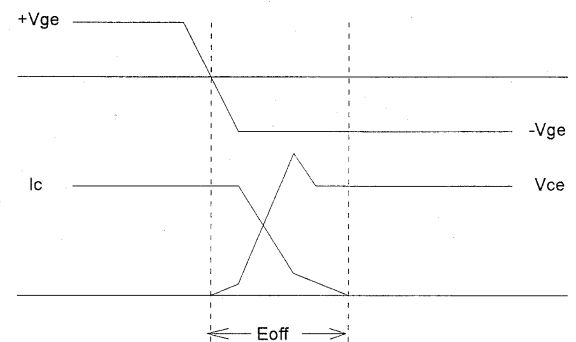
Test Circuit



Switching waveforms



Turn-on Waveforms



Turn-off Waveforms